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## GENERAL DESCRIPTION

The HI-8200 is a quad analog CMOS switch fabricated with Sili-con-on-Insulator (SOI) technology for latch-up free operation and maximum switch isolation. High voltage gate drive is entirely created on-chip enabling +/-12V switching range from a single 3.3 V or 5 V supply. These switches are ideally suited for applications demanding low switch leakage when the power pins are $0 V$.

At $25^{\circ} \mathrm{C}$ and with VDD from 3.0 V to 5.5 V , the switch resistance (RON) is typically $8 \Omega$. RON is independent of VDD. In a switching range of -5 V to +5 V , the maximum deviation of RON from flat is less than $5 \%$.

These switches conduct equally well in either direction. Power down and Off state leakages are less than 10nA maximum. Charge injection is less than 10pC. Switching times are typically 180 ns to the On state and 60 ns to the Off state. The onboard charge pump allows an On/Off cycle time of 5 KHz for all four switches simultaneously before the switching range becomes restricted.

The HI-8200 provides four each normally open switches when the switch control inputs are low. The HI-8201 provides four each normally closed switches when the switch control inputs are low. The HI-8202 provides a combination of two normally closed and two normally open switches.

Industry-standard plastic package options include 20-pin TSSOP, 16-pin DIP and 16-pin QFN. Ceramic packaging is available on request. All three products are offered in both industrial $\left(-40^{\circ} \mathrm{C}\right.$ to $\left.+85^{\circ} \mathrm{C}\right)$ and extended $\left(-55^{\circ} \mathrm{C}\right.$ to $\left.+125^{\circ} \mathrm{C}\right)$ temperature range options.

## APPLICATIONS

- Avionics
- Data bus isolation
- Sample-and-Hold circuits
- Test Equipment
- Communications Systems


## FEATURES

- CMOS analog switches with up to +/-12V switching range from a single 3.3 V or 5 V supply
- Low RON: $10 \Omega$ max at $25^{\circ} \mathrm{C}$
- Robust CMOS Silicon-on-Insulator (SOI) technology
- Switch nodes are open-circuit when chip is powered down
- SOI switch isolation with 1nA typical Off leakage
- ESD protection > 4KV HBM
- Fast switching time with break-before-make
- Low power
- Extended Temperature Range $\left(-55^{\circ} \mathrm{C}\right.$ to $\left.+125^{\circ} \mathrm{C}\right)$


## PIN CONFIGURATIONS (Top Views)



HI-8200PCx
16-pin $5 \mathrm{~mm} \times 5 \mathrm{~mm}$ Chip-scale package (see page 6 for additional package configurations)

| PRODUCT OPTIONS |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| PART TYPE | IN1 | Switch 1 | IN2 | Switch 2 | IN3 | Switch 3 | IN4 | Switch 4 |
| HI-8200 | 0 | Open | 0 | Open | 0 | Open | 0 | Open |
|  | 1 | Closed | 1 | Closed | 1 | Closed | 1 | Closed |
| HI-8201 | 0 | Closed | 0 | Closed | 0 | Closed | 0 | Closed |
|  | 1 | Open | 1 | Open | 1 | Open | 1 | Open |
| HI-8202 | 0 | Open | 0 | Closed | 0 | Closed | 0 | Open |
|  | 1 | Closed | 1 | Open | 1 | Open | 1 | Closed |

## PIN DESCRIPTIONS

| SIGNAL | FUNCTION | DESCRIPTION |
| :---: | :---: | :--- |
| IN1 | Logic Input | HI-8200 and HI-8202 are normally Open when input Low |
| S1A | Switch Node | Switch 1 Node |
| S1B | Switch Node | Switch 1 Node |
| V- | CAP - | Bulk storage capacitor. Add 0.1uF ceramic capacitor to GND. (20V or higher). |
| GND | Supply | Reference Ground |
| S4B | Switch Node | Switch 4 Node |
| S4A | Switch Node | Switch 4 Node |
| IN4 | Logic Input | HI-8200 and HI-8202 are normally Open when input Low |
| IN3 | Logic Input | HI-8201 and HI-8202 are normally Closed when input Low |
| S3A | Switch Node | Switch 3 Node |
| S3B | Switch Node | Switch 3 Node |
| VLOGIC | Supply | 3.3V or 5.0V Logic supply |
| V+ | CAP + | Bulk storage capacitor. Add 0.1uF ceramic capacitor to GND. (20V or higher). |
| S2B | Switch Node | Switch 2 Node |
| S2A | Switch Node | Switch 2 Node |
| IN2 | Logic input | HI-8201 and HI-8202 are normally Closed when input Low |

NOTE: V+ and V - pins are only to be used for connection of bulk storage capacitors and MUST NOT be loaded.


Typical Ron as a function of Vswitch and Temperature ( 10 mA switch current, Vsupply $=+3.3 \mathrm{~V}$ )

## ABSOLUTE MAXIMUM RATINGS

(Voltages referenced to GND $=0 \mathrm{~V}$ )

| Supply Voltage, VLOGIC ...............................................................7.0 | Continuous Power Dissipation ( $\mathrm{TA}=70^{\circ} \mathrm{C}$ ): |  |
| :---: | :---: | :---: |
| Switch Current (either direction, DC): ........................................... 20 mA | SO Package (derate $6.7 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $70^{\circ} \mathrm{C}$ )................ 696 mW |  |
| Peak Switch Current (1 ms pulse, 10\% duty cycle max.)................100mA | Plastic DIP (derate $10.53 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $70^{\circ} \mathrm{C}$ )................... 842 mWThin QFN (derate $21.3 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $70^{\circ} \mathrm{C}$ ) ............. 1702 mW |  |
| Digital Input Voltage (IN1-4):................................-0.3V to VLocic + 0.3V |  |  |
|  | Storage Temperature Range: | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
|  | Soldering Temperature: | (Ceramic)..................... 60 sec. at $+300^{\circ} \mathrm{C}$ (Plastic- -leads)......... 10 sec. at $+280^{\circ} \mathrm{C}$ |
| Maximum Junction Temperature ................................................ $175^{\circ} \mathrm{C}$ |  | (Plastic - body) ................... $+260^{\circ} \mathrm{C}$ Max. |

NOTE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only.
Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied.
Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## ELECTRICAL CHARACTERISTICS

VLOGIC $=3.3 \mathrm{~V}$ or 5.0 V , GND $=0 \mathrm{~V}$. Operating temperature range (unless otherwise noted).

| PARAMETER | SYMBOL | CONDITIONS | FIGURE | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| SWITCH PARAMETERS |  |  |  |  |  |  |  |
| Switch Resistance, $25^{\circ} \mathrm{C}$, 10 mA | Ron | $12 \mathrm{~V}>\mathrm{Vs}>-12 \mathrm{~V}$ | 1 | 6 | 8 | 10 | $\Omega$ |
| Leakage - (open circuit and power down) | \|ISWLEAK| | $12 \mathrm{~V}>\mathrm{Vs}>-12 \mathrm{~V}$ | 2 |  | 1 | 10 | nA |
| Leakage - (open circuit and power on) | \|ISWLEAKp| | $12 \mathrm{~V}>\mathrm{Vs}>-12 \mathrm{~V}$ | 2 |  | 1 | 100 | nA |
| LOGIC INPUTS |  |  |  |  |  |  |  |
| Input High Voltage | VIH |  |  | 75\% |  |  | V |
| Input Low Voltage | VIL |  |  |  |  | 25\% | V |
| Input Current | IIH <br> IIL | 80K Ohm pulldown <br> VLogic $=3.3 \mathrm{~V}$ <br> Vlogic $=5.0 \mathrm{~V}$ |  |  | $\begin{aligned} & 45 \\ & 65 \end{aligned}$ | 0.5 | $\mu \mathrm{A}$ $\mu \mathrm{A}$ $\mu \mathrm{A}$ |
| SUPPLY |  |  |  |  |  |  |  |
| VLogic Operating Range | VDD |  |  | 3.0 |  | 5.5 | V |
| VLogic Operating Current | IDD | inputs static <br> VLogic $=3.3 \mathrm{~V}$ <br> Vlogic $=5.0 \mathrm{~V}$ |  |  |  | $\begin{aligned} & 1.0 \\ & 2.5 \end{aligned}$ | $\underset{\mathrm{mA}}{\mathrm{~mA}}$ |
| DYNAMIC PARAMETERS |  |  |  |  |  |  |  |
| Max Vin On/Off cycling | fcycle | any load |  |  |  | 5 | Khz |
| Turn On Time | Ton |  | 3 |  | 180 | 250 | ns |
| Turn Off time | Toff |  | 3 |  | 80 | 150 | ns |
| Break-Before-Make Time | TD |  | 4 | 40 | 80 |  | ns |
| Charge Injection | Q | $\mathrm{Vs}=0 \mathrm{~V}, \mathrm{Rs}=0 \Omega, 25^{\circ} \mathrm{C}$ | 5 |  | -20 |  | pC |
| Off Isolation | RR | $\mathrm{f}=1 \mathrm{MHz}, 25^{\circ} \mathrm{C}$ | 6 |  | 65 |  | dB |
| Crosstalk | CR | $\mathrm{f}=1 \mathrm{MHz}, 25^{\circ} \mathrm{C}$ | 7 |  | 90 |  | dB |
| Capacitance | Coff Con | Switch Off, $25^{\circ} \mathrm{C}$ Switch On, $25^{\circ} \mathrm{C}$ | $\begin{aligned} & 8 \\ & 9 \end{aligned}$ |  | $\begin{aligned} & 15 \\ & 60 \end{aligned}$ |  | $\begin{aligned} & \mathrm{pF} \\ & \mathrm{pF} \end{aligned}$ |
| Charge Pump Power On | Tvon | $\begin{gathered} \mathrm{V}+\text { and } \mathrm{V}-=+/-14.5 \mathrm{~V} \\ \mathrm{~V} \text { Logic }=5.0 \mathrm{~V} \end{gathered}$ | 10 | 10 |  |  | ms |

## TEST CIRCUITS



Figure 1-On Resistance


Figure 2-Off Leakage


Figure 3. Switching Times


Figure 4. Break-Before-Make Time Delay (HI-8202)


Figure 5. Charge Injection


Figure 6-Off Isolation


Figure 8 - Off Capacitance



Figure 10. Charge Pump Power On

## Additional package configurations



## ORDERING INFORMATION

HI - 820x

## REVISION HISTORY

| P/N | Rev | Date | Description of Change |
| :--- | :---: | :---: | :--- |
| DS8200 | New | $10 / 18 / 12$ | Initial Release |
|  | A | $10 / 22 / 12$ | Remove 1MOhm resistor to GND from test circuits. Correct typo in Pin Descriptions |
|  | B | $12 / 18 / 12$ | Clarify that $V+/ V$ - pins must not be loaded. Used only for connection of bulk storage caps. |
|  | C | $04 / 18 / 16$ | Add leakage spec for power on condition. |

## 20-PIN PLASTIC TSSOP

inches (millimeters)
Package Type: 20HS

is Basic Spacing is theoretical true position dimension and has no tolerance. (JEDEC Standard 95)

## 16-PIN PLASTIC CHIP-SCALE PACKAGE

## millimeters

Package Type: 16PCS1

$0.75 \pm 0.05$
( $0.03 \pm 0.002$ )


BSC $=$ "Basic Spacing between Centers" is theoretical true position dimension and has no tolerance. (JEDEC Standard 95)

## 16-PIN PLASTIC DIP


inches (millimeters)

